

Features

- Frequency: 2GHz~8GHz
- Small Signal Gain: 33dB
- Output Power: 44dBm CW
- Package: Bare die
- Supply Voltage: +28V/-Vg

Typical Applications

- Point-to-Point Radios

General Description

SAC5022 is a 2GHz to 8GHz wideband power amplifier with a saturated output power (P_{OUT}) of 44dBm, power added efficiency (PAE) of 30%, and a power gain of 25dB typical from 2GHz to 8GHz at input power (P_{IN}) of 25dBm. The RF input and RF output are internally matched.

Electrical Performance

$T_{BASE}=23^{\circ}C$, $V_D=+28V$, $I_{DQ}=1.4A$, $Z_0=50\Omega$, CW

| Parameter | Min. | Typ. | Max. | Units |
|---------------------------|------|------|------|-------|
| Frequency Range | 2 | — | 8 | GHz |
| Small Signal Gain | — | 33 | — | dB |
| Power Gain | — | 25 | — | dB |
| Reverse Isolation | — | 50 | — | dB |
| RF Input Port Return Loss | — | 9 | — | dB |
| Output Power | 43 | 44 | — | dBm |
| Drain Voltage (V_D) | — | 28 | — | V |
| Gate Current | — | — | 21 | mA |
| Supply Current (I_D)* | — | — | 5 | A |

*Adjust Vg between -2.5V to -1.7V to achieve $I_{DQ1}=1.4A$

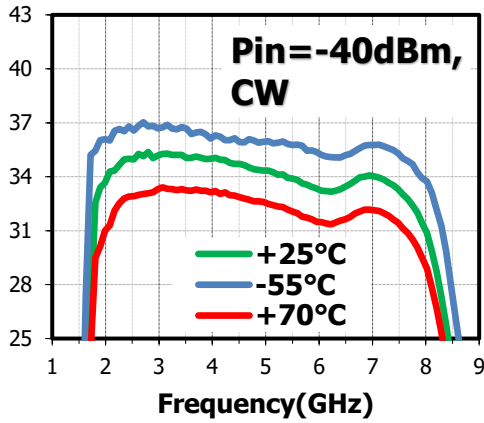
Absolute Maximum Ratings

| | | | |
|-----------------------------------|--------|--------------------------------------|--------------|
| Maximum Input Power | +28dBm | Operating Temperature (T_{BASE}) | -55°C~+85°C |
| Channel Temperature | 230°C | Storage Temperature | -55°C~+180°C |
| Maximum V_D | +32V | V_G Range | -10V~-1.5V |
| Mounting Temperature (30 seconds) | 320°C | | |

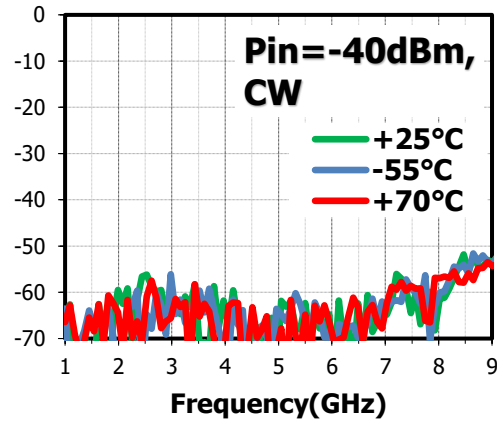
Typical Performance Curve

$V_D = +28V$, $I_{DQ} = 1.4A$, $T_{BASE} = +23^{\circ}C$, CW

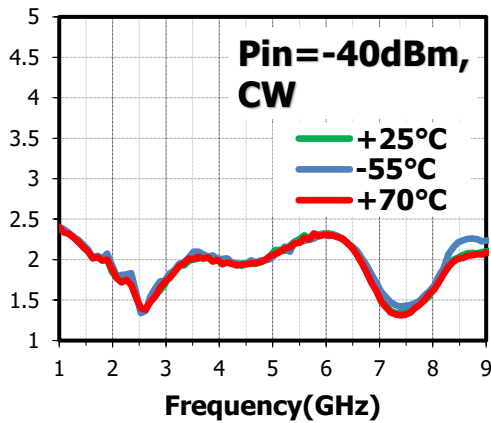
Small Signal Gain(dB) vs. Temperature



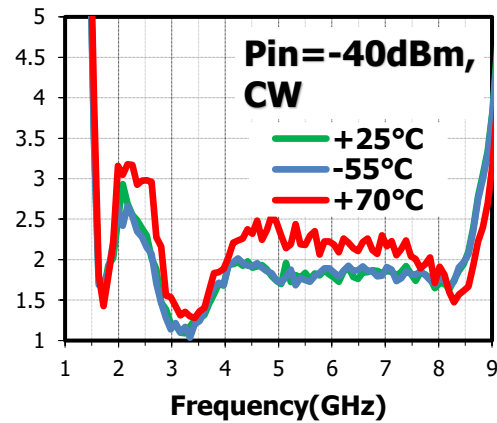
Isolation(dB) vs. Temperature



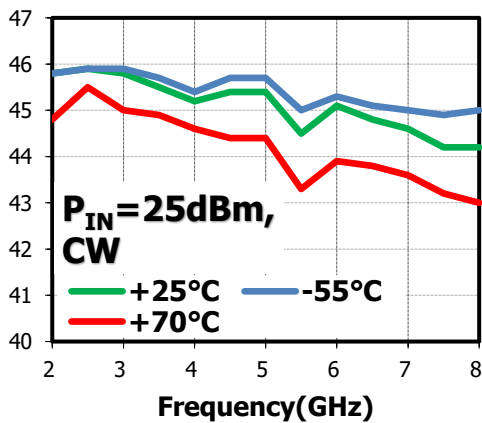
Input VSWR(:1) vs. Temperature



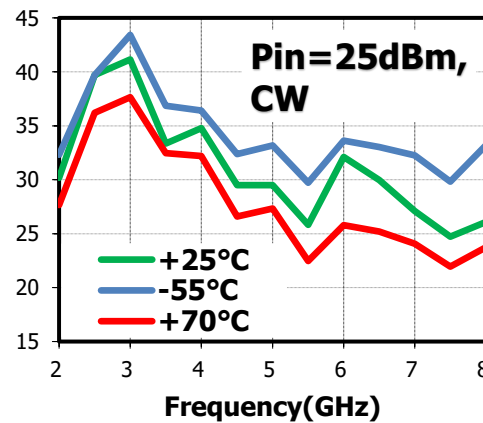
Output VSWR(:1) vs. Temperature



Output Power(dBm) vs. Frequency



PAE(%) vs. Frequency



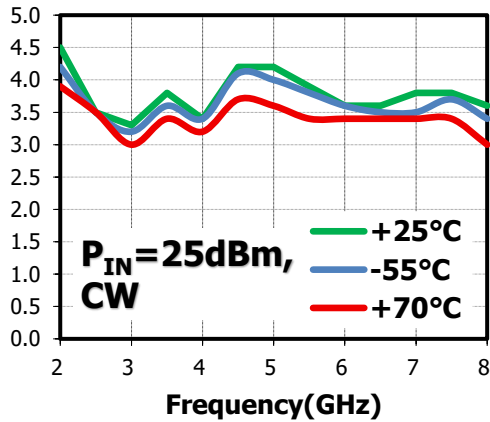
SAC5022



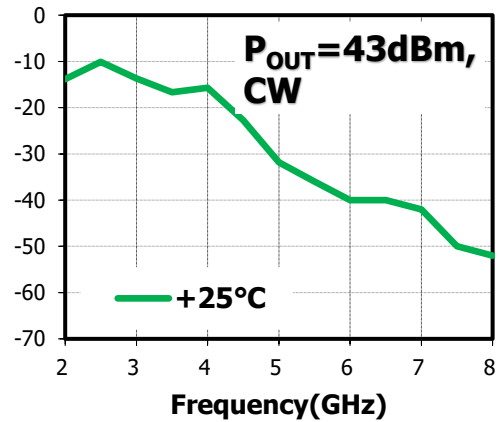
GaN MMIC Power Amplifier
2GHz~8GHz 44dBm

Rev 1.0

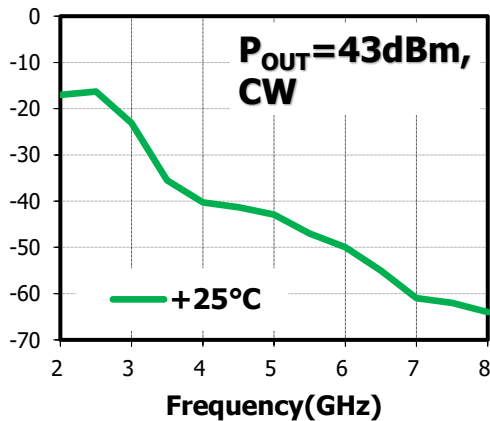
I Drain(A) vs.Frequency



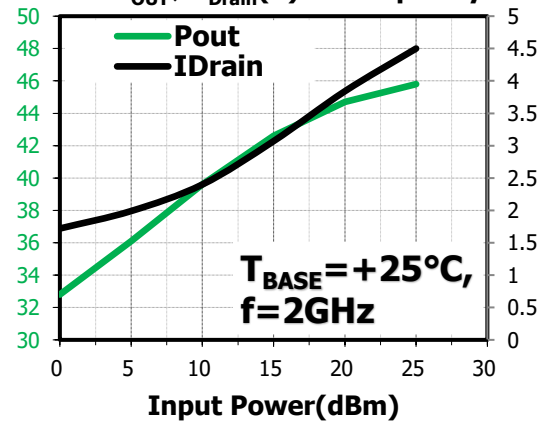
2nd Harmonic(dBc) vs.Frequency



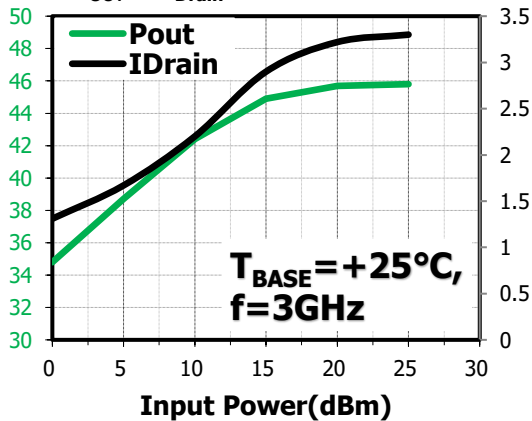
3rd Harmonic(dBc) vs.Frequency



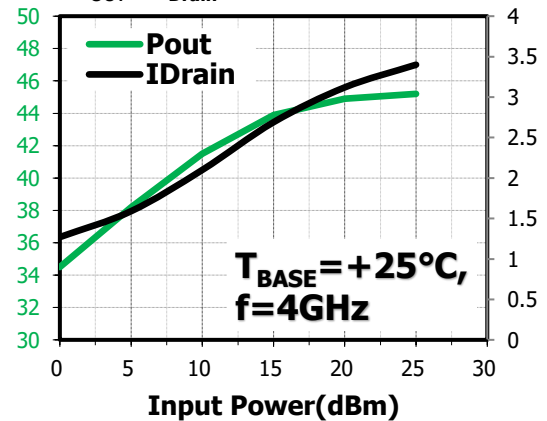
P_{OUT} , I_{Drain} (A) vs.Frequency



P_{OUT} , I_{Drain} (A) vs.Frequency

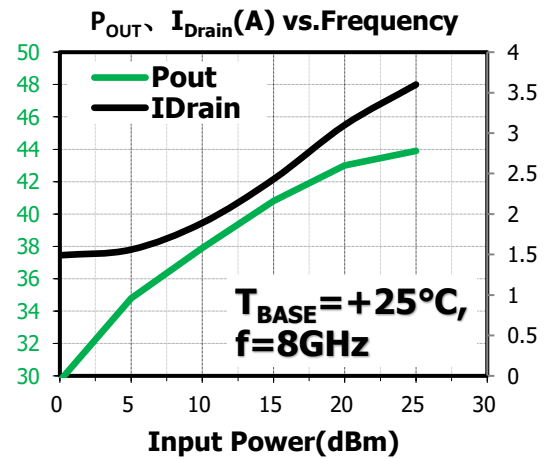
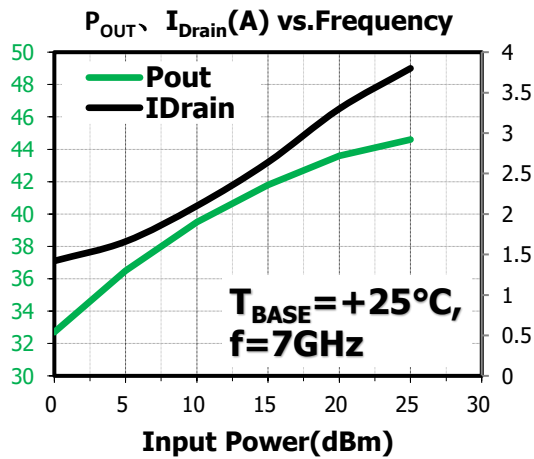
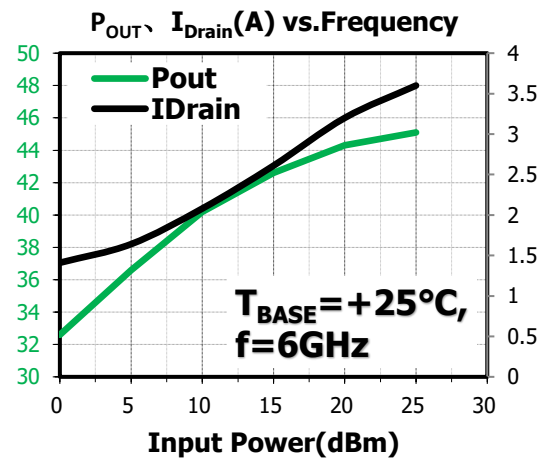
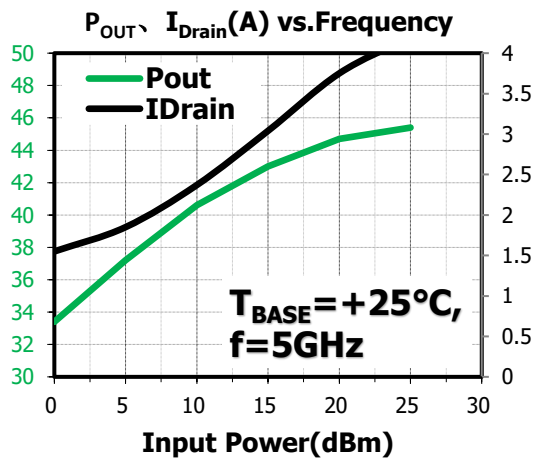


P_{OUT} , I_{Drain} (A) vs.Frequency



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Thermal Resistance

| Parameter | Conditions | Value | Unit |
|----------------|--|-------|------|
| θ_{JC1} | VD=+28V, T _{BASE} =+70°C, Pin=+25dBm, CW, f=6GHz | 0.88 | °C/W |

Electrostatic Discharge (ESD) Ratings

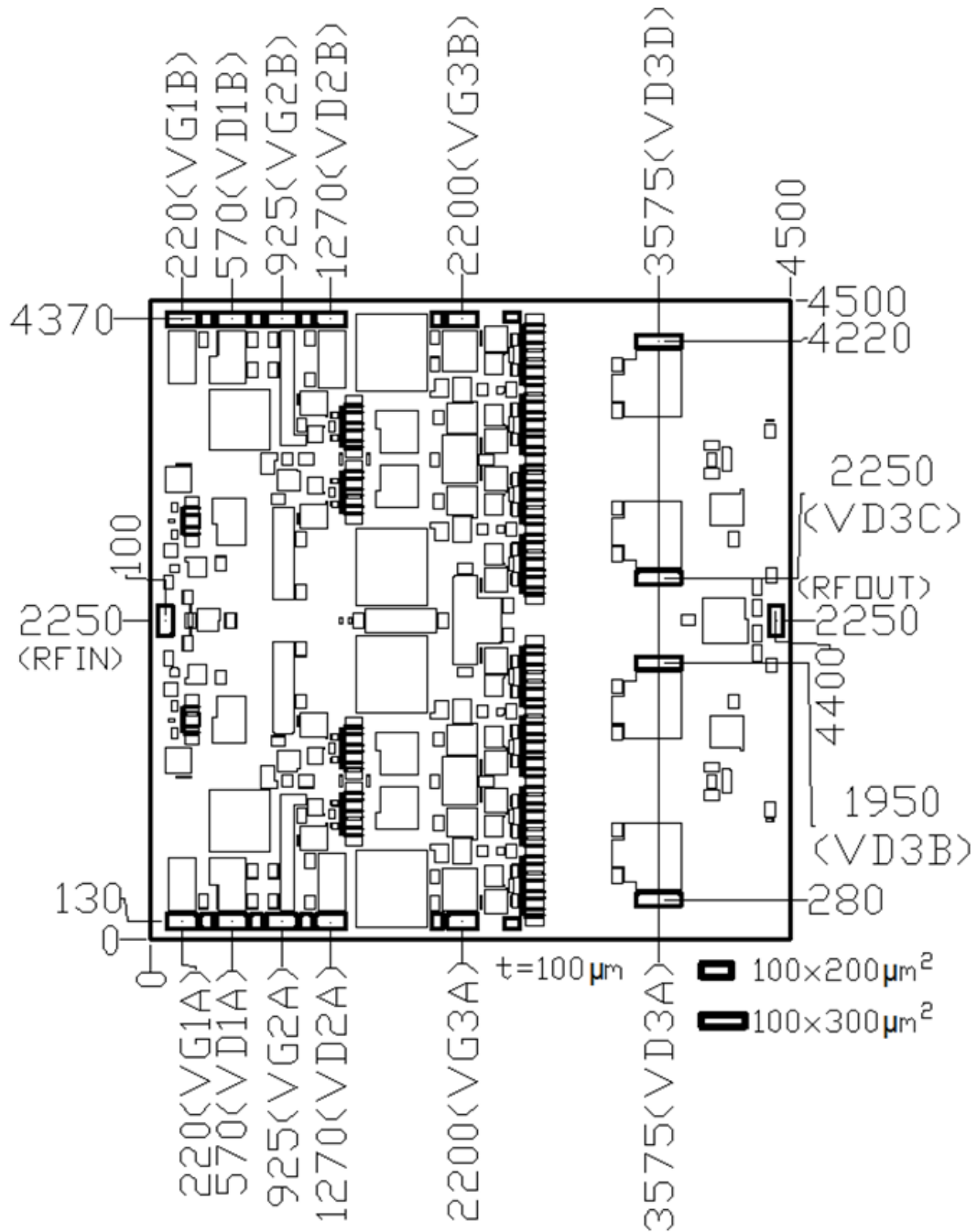
| ESD Model | Conditions | Withstand Threshold (V) | Class |
|-----------|--|-------------------------|-------|
| HBM | Human body model (HBM) per ANSI/ESDA/JEDEC JS-001 | 500 | 1B |

SAC5022

GaN MMIC Power Amplifier
2GHz~8GHz 44dBm

Rev 1.0

Bare Die Outline (μm)



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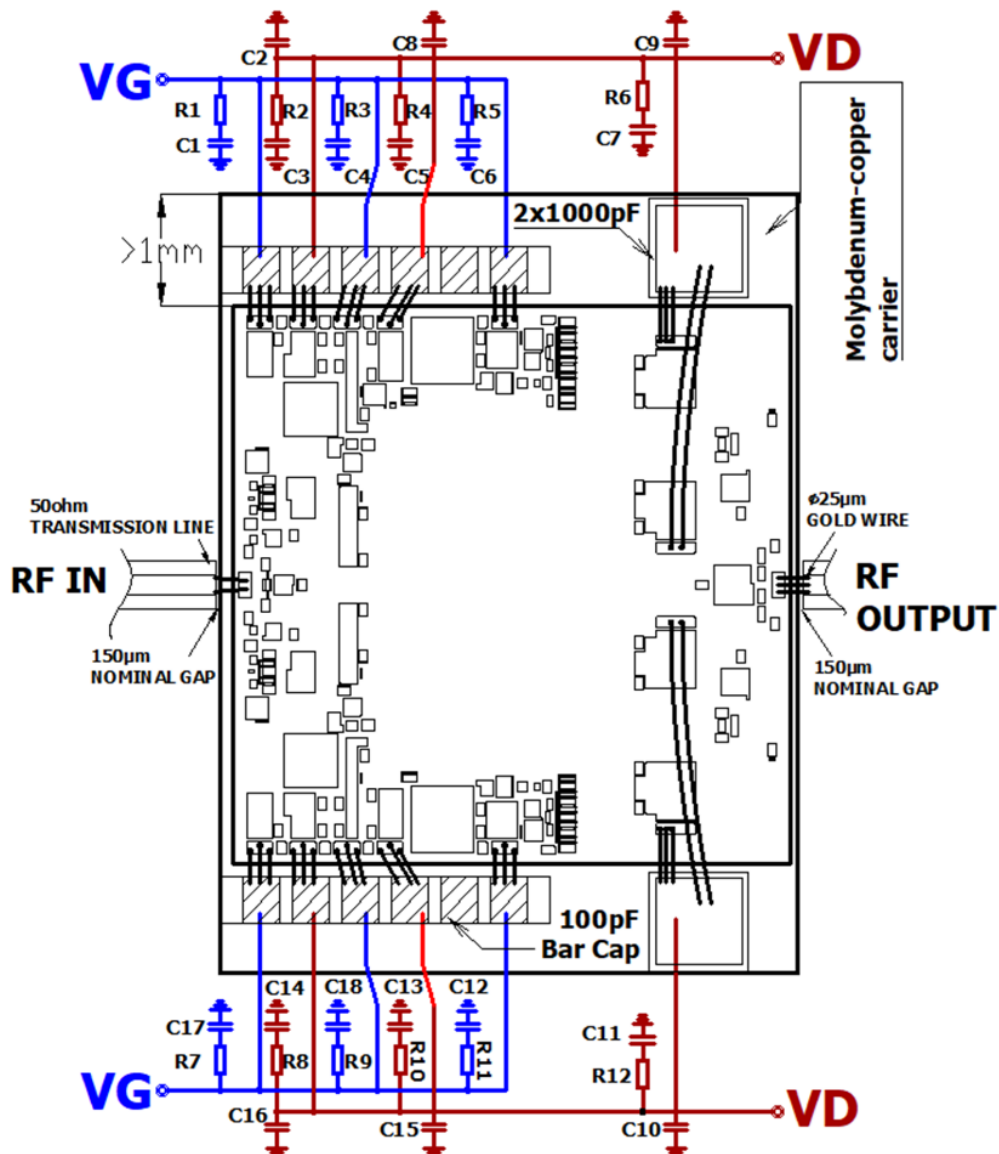
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Application Circuit



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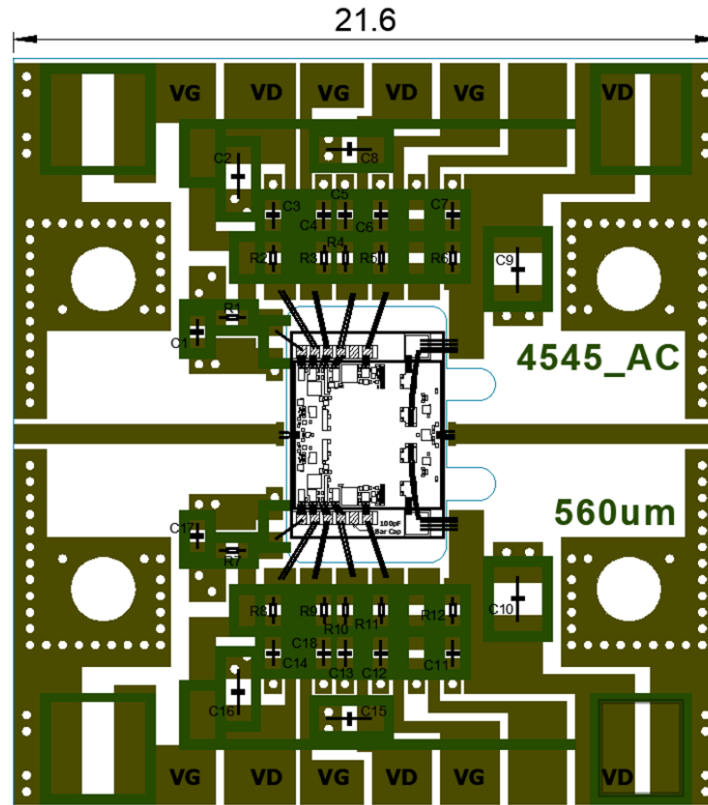
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SAC5022 EVB



BOM

| Reference Des. | Part Number | Value | Size |
|--------------------------|---------------|-------------------|------|
| R1~R12 | - | 2.2 Ω | 0402 |
| C1、C3~C7、C11~C14、C17、C18 | - | 0.047 μ F | 0402 |
| C2、C8、C15、C16 | - | 4.7 μ F | 0603 |
| C9、C10 | - | 10 μ F | 0805 |
| - | PCB | Ro4350b, t=0.254 | |
| - | MoCu Heatsink | Mo70, 4.6x6.6x0.2 | |

Notes

- SAC5022 requires VDx and VGx bias,
Turn-on: Apply VGx, Apply VDx, Apply RFIN signal,
Turn-off: Remove RFIN signal, Decrease VG to -5V(pinch-off), Decrease VD to 0 V;
- Suggest molybdenum-copper heatsink thickness is 0.2mm;
- Microelectronic devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly, and test;
- Each VD and Vg pin (VD1x,2x,3x and VG1x,2x,3x) needs to have bypass capacitors (bar cap) mounted as close to the MMIC as possible;
- The loop height of the VD and VG bonds should be minimized.

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SAC5022



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2GHz~8GHz 44dBm

Rev 1.0

Revision History

| Revision | Date | Comment |
|----------|--------------|---------------|
| 1.0 | Jul. 8, 2025 | First Release |
| | | |
| | | |

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